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## Synthesis of ZnO Thin Films Using the Sol-Gel Method and Ion Beam Irradiation

Thursday, November 14, 2024 2:30 PM (20 minutes)

ZnO thin films are semiconductor films used in LEDs. Using the sol-gel method, a ZnO precursor solution is prepared and deposited via spin-coating. Subsequent heat treatment at temperatures above 200°C results in the formation of ZnO thin films. However, when utilizing ZnO thin films on flexible substrates, the temperature cannot exceed 200°C. Additionally, ZnO thin films produced at 200°C contain residual organic compounds, necessitating heat treatment above 300°C. To address this issue, we propose the fabrication of ZnO thin films using ion beam irradiation. This method aims to achieve high-temperature annealing effects on the surface and verify the synthesis of ZnO thin films. Furthermore, techniques such as FT-IR will be employed to analyze the composition of residual organic materials and compare the differences with conventional methods.

## Paper submission Plan

**Best Presentation** 

## **Contribution track**

KOPUA

**Primary authors:** JEON, Gi Wan (Korea Multi-purpose Accelerator Complex, Korea Atomic Energy Research Institute, Gyeongju, Gyeongbuk, 38180, Republic of Korea); Dr PARK, Jun Kue (Korea Multi-purpose Accelerator Complex, Korea Atomic Energy Research Institute, Gyeongju, Gyeongbuk, 38180, Republic of Korea)

**Presenter:** JEON, Gi Wan (Korea Multi-purpose Accelerator Complex, Korea Atomic Energy Research Institute, Gyeongju, Gyeongbuk, 38180, Republic of Korea)

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